



SANYO Semiconductors

# DATA SHEET

An ON Semiconductor Company

## CPH6121 — PNP Epitaxial Planar Silicon Transistor DC / DC Converter Applications

### Applications

- Relay drivers, lamp drivers, motor drivers, strobes

### Features

- Adoption of MBIT process
- High current capacitance
- Low collector-to-emitter saturation voltage
- High speed switching
- Ultrasmall-sized package permitting applied sets to be made small and slim (0.9mm)
- High allowable power dissipation

### Specifications

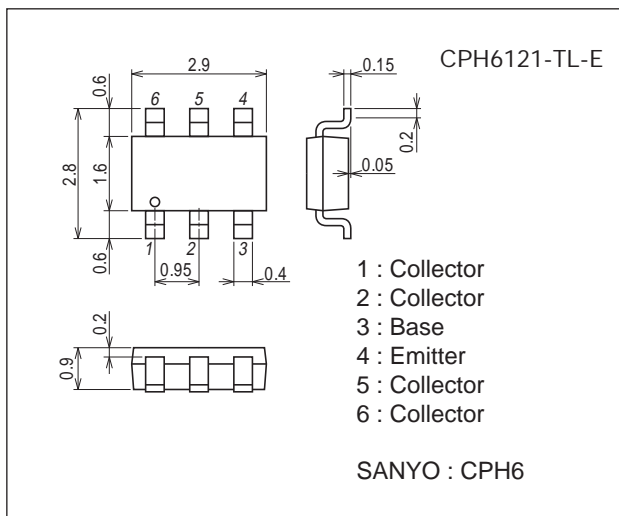
Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V <sub>CB0</sub>		-15	V
Collector-to-Emitter Voltage	V <sub>CEO</sub>		-12	V
Emitter-to-Base Voltage	V <sub>EBO</sub>		-5	V
Collector Current	I <sub>C</sub>		-3	A
Collector Current (Pulse)	I <sub>CP</sub>		-5	A
Base Current	I <sub>B</sub>		-600	mA
Collector Dissipation	P <sub>C</sub>	Mounted on a ceramic board (600mm <sup>2</sup> ×0.8mm)	1.3	W
Junction Temperature	T <sub>J</sub>		150	°C
Storage Temperature	T <sub>stg</sub>		-55 to +150	°C

### Package Dimensions

unit : mm (typ)

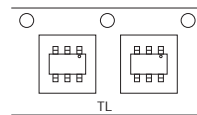
7018A-002



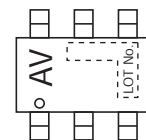
### Product & Package Information

- Package : CPH6
- JEITA, JEDEC : SC-74, SOT-26, SOT-457
- Minimum Packing Quantity : 3,000 pcs./reel

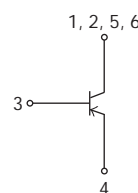
### Packing Type: TL



### Marking



### Electrical Connection

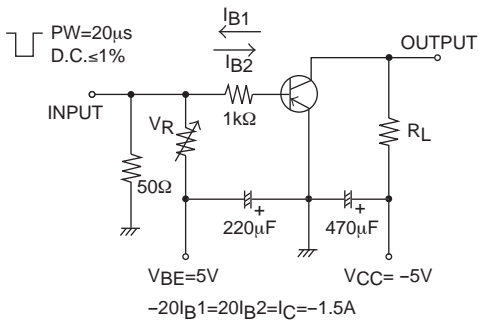


# CPH6121

## Electrical Characteristics at Ta=25°C

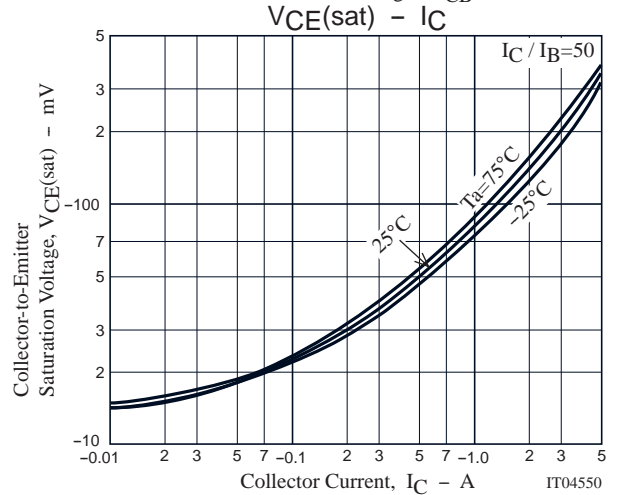
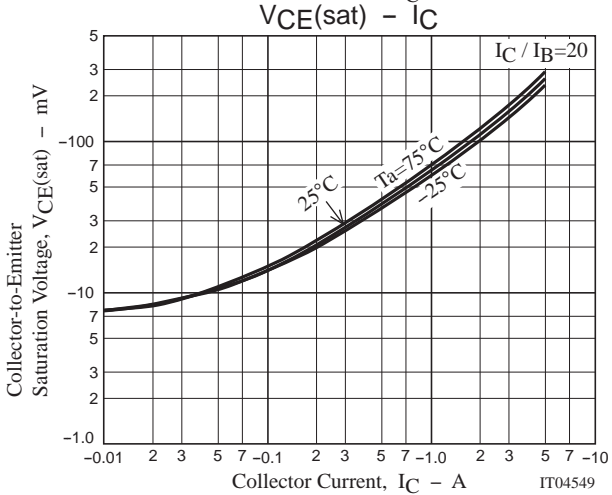
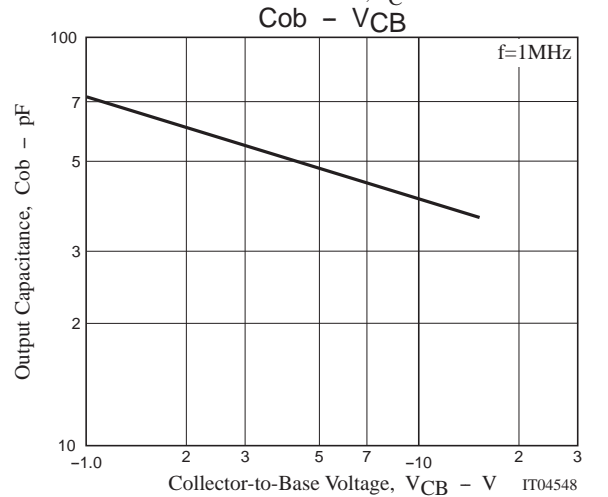
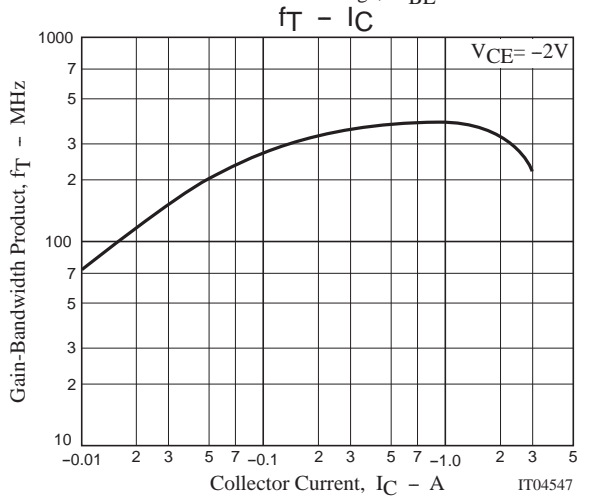
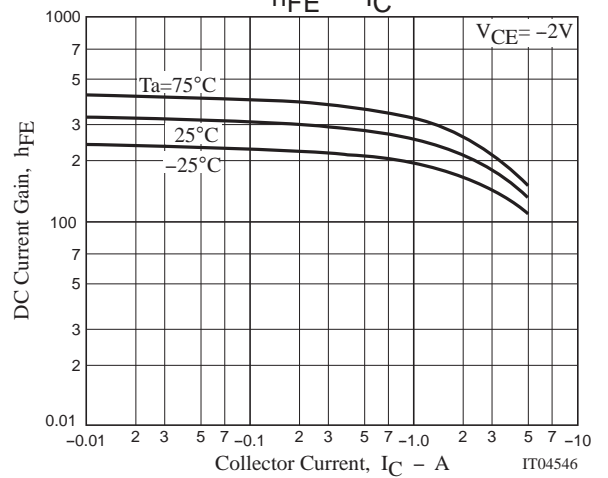
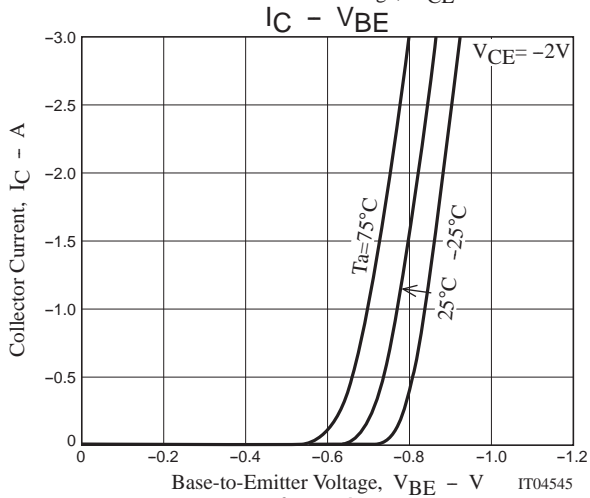
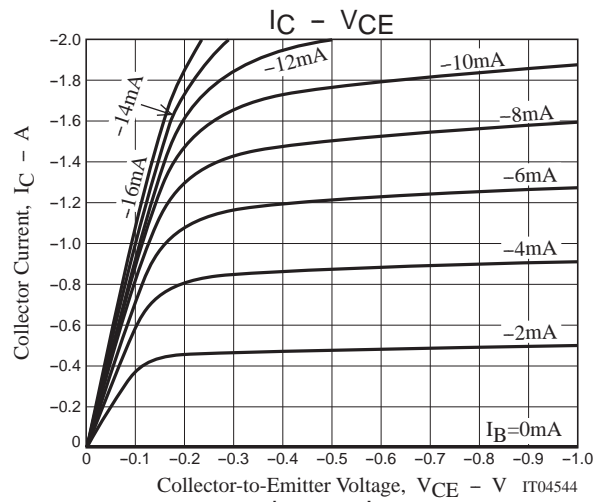
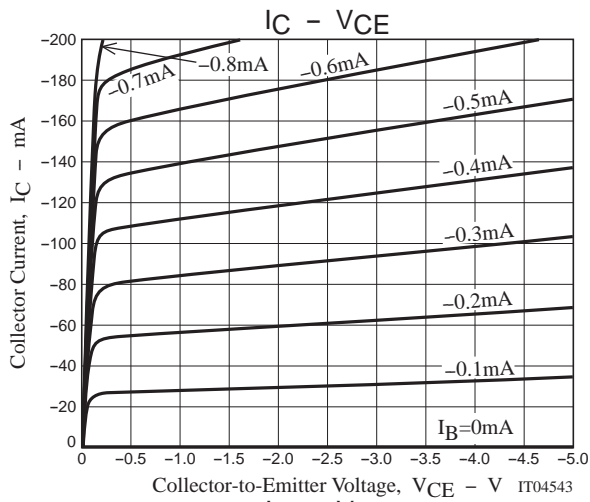
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector Cutoff Current	$I_{CBO}$	$V_{CB} = -12V, I_E = 0A$			-0.1	$\mu A$
Emitter Cutoff Current	$I_{EBO}$	$V_{EB} = -4V, I_C = 0A$			-0.1	$\mu A$
DC Current Gain	$h_{FE}$	$V_{CE} = -2V, I_C = -500mA$	200		560	
Gain-Bandwidth Product	$f_T$	$V_{CE} = -2V, I_C = -500mA$		380		MHz
Output Capacitance	$C_{ob}$	$V_{CB} = -10V, f = 1MHz$		40		pF
Collector-to-Emitter Saturation Voltage	$V_{CE(sat)}$	$I_C = -1.5A, I_B = -30mA$		-110	-165	mV
Base-to-Emitter Saturation Voltage	$V_{BE(sat)}$	$I_C = -1.5A, I_B = -30mA$		-0.85	-1.2	V
Collector-to-Base Breakdown Voltage	$V_{(BR)CBO}$	$I_C = -10\mu A, I_E = 0A$	-15			V
Collector-to-Emitter Breakdown Voltage	$V_{(BR)CEO}$	$I_C = -1mA, R_{BE} = \infty$	-12			V
Emitter-to-Base Breakdown Voltage	$V_{(BR)EBO}$	$I_E = -10\mu A, I_C = 0A$	-5			V
Turn-On Time	$t_{on}$	See specified Test Circuit.		30		ns
Storage Time	$t_{stg}$			90		ns
Fall Time	$t_f$			14		ns

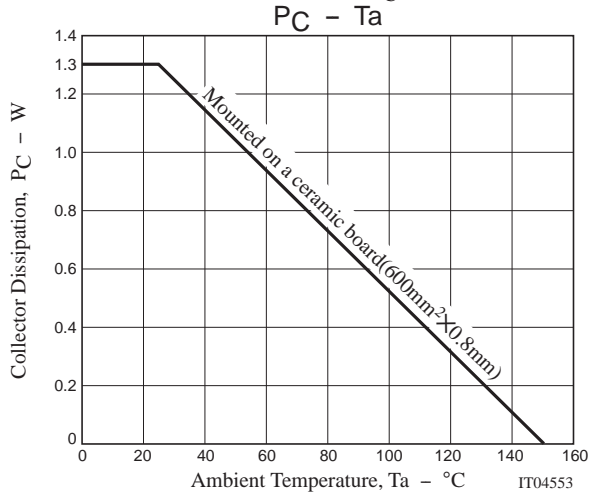
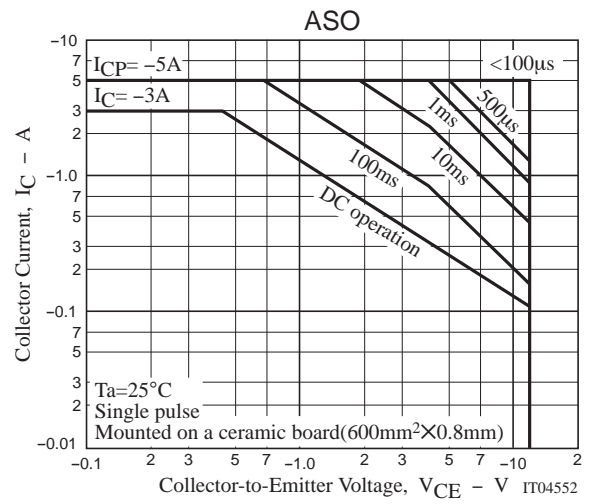
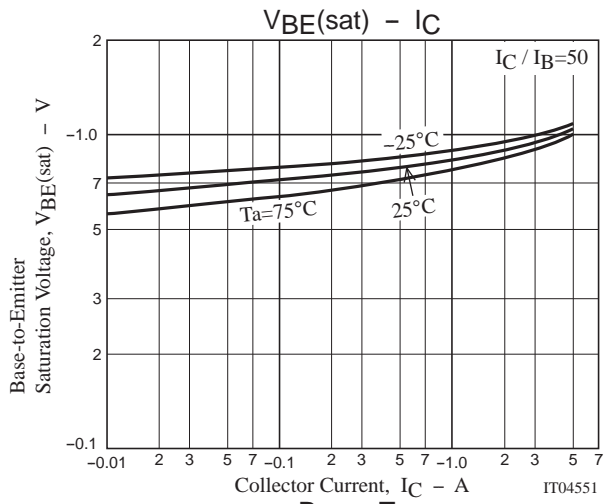
## Switching Time Test Circuit



## Ordering Information

Device	Package	Shipping	memo
CPH6121-TL-E	CPH6	3,000pcs./reel	Pb Free



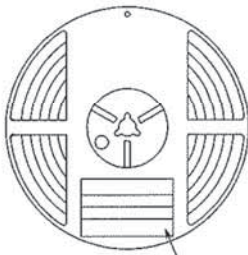


Embossed Taping Specification  
CPH6121-TL-E

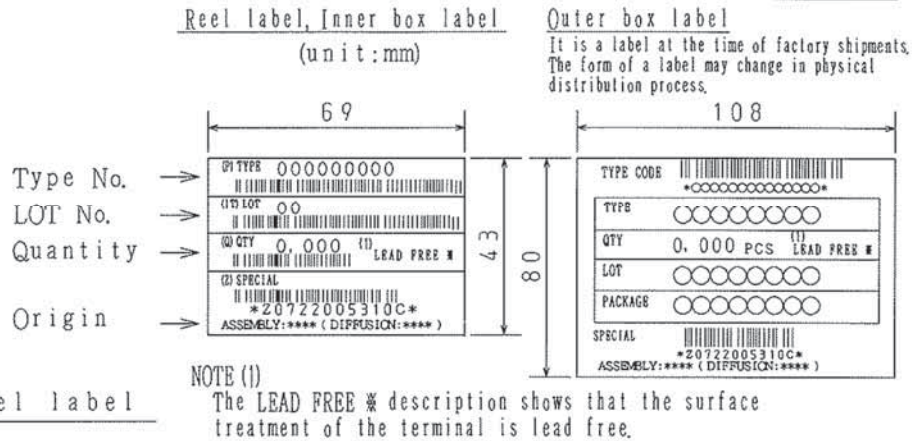
1. Packing Format

Package Name	Carrier Tape Type	Maximum Number of devices contained (pcs)			Packing format	
		Reel	Inner box	Outer box	Inner BOX (C-1)	Outer BOX (A-7)
CPH6	CPH6	3,000	15,000	90,000	5 reels contained Dimensions:mm (external) 183×72×185	6 inner boxes contained Dimensions:mm (external) 440×195×210

Packing method



Reel label



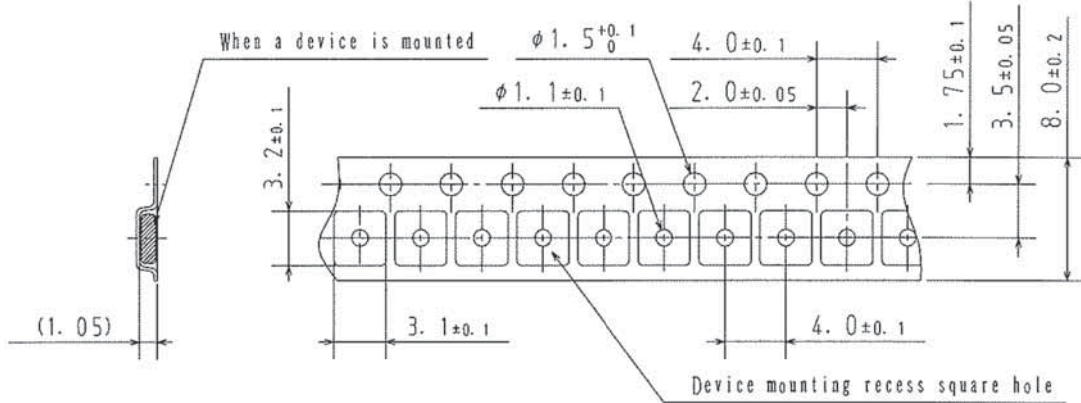
NOTE (1)

The LEAD FREE \* description shows that the surface treatment of the terminal is lead free.

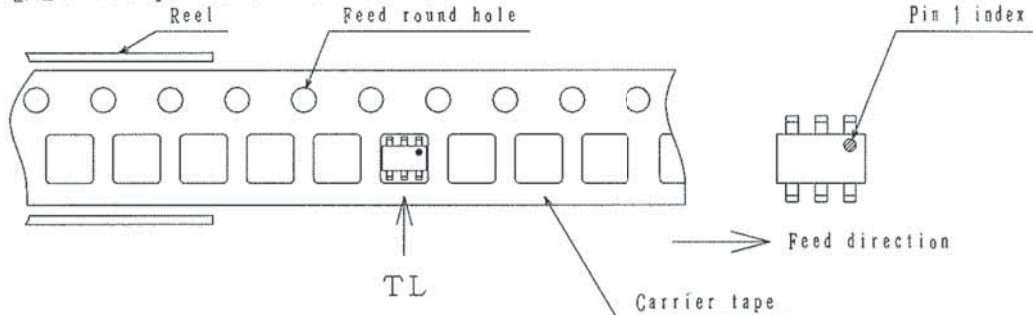
Label	JEITA Phase
LEAD FREE 3	JEITA Phase 3A
LEAD FREE 4	JEITA Phase 3

2. Taping configuration

2-1. Carrier tape size (unit:mm)



2-2. Device placement direction

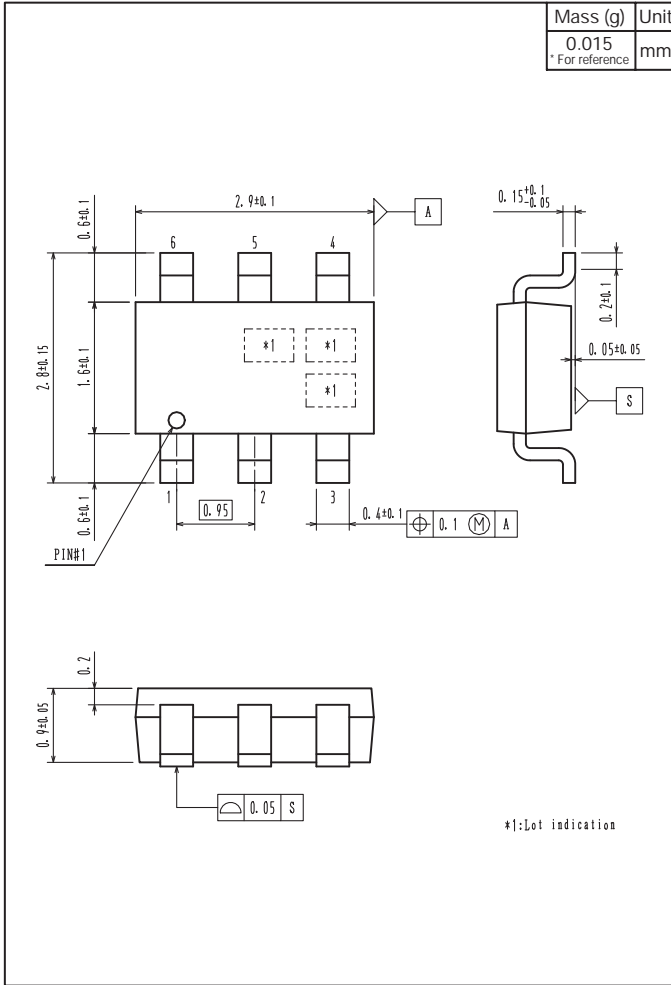


Those with pin 1 index on the feed hole side.....TL

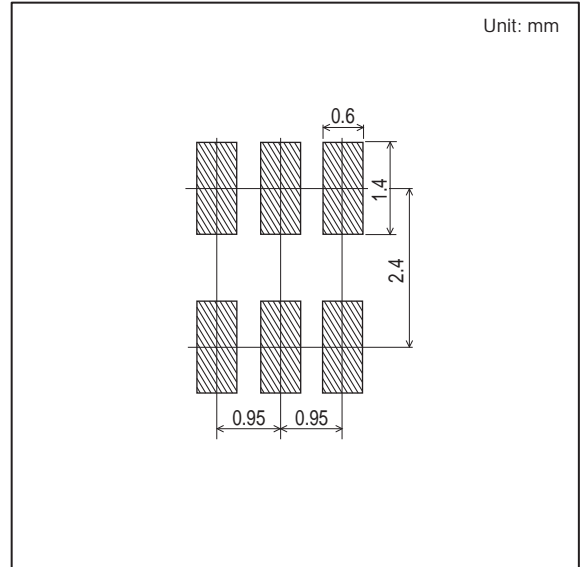
# CPH6121

## Outline Drawing

CPH6121-TL-E



## Land Pattern Example



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